# **NTS0102**

# Dual supply translating transceiver; open drain; auto direction sensing

Rev. 4 — 23 January 2013

**Product data sheet** 

### 1. General description

The NTS0102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ).  $V_{CC(A)}$  can be supplied at any voltage between 1.65 V and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 2.3 V and 5.5 V, making the device suitable for translating between any of the voltage nodes (1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins An and OE are referenced to  $V_{CC(A)}$  and pins Bn are referenced to  $V_{CC(B)}$ . A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range:
  - ♦ V<sub>CC(A)</sub>: 1.65 V to 3.6 V and V<sub>CC(B)</sub>: 2.3 V to 5.5 V
- Maximum data rates:
  - ◆ Push-pull: 50 Mbps
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
  - ◆ HBM JESD22-A114E Class 2 exceeds 2500 V for A port
  - ◆ HBM JESD22-A114E Class 3B exceeds 8000 V for B port
  - ♦ MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1500 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Applications

- I<sup>2</sup>C/SMBus
- UART
- GPIO



### Dual supply translating transceiver; open drain; auto direction sensing

# 4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
NTS0102DP	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
NTS0102GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 $\times$ 1.95 $\times$ 0.5 mm	SOT833-1
NTS0102GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm	SOT996-2
NTS0102GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 $\times$ 1 $\times$ 0.5 mm	SOT1089
NTS0102GU	–40 °C to +125 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 $\times$ 1.80 $\times$ 0.50 mm	SOT1160-1
NTS0102GU8	–40 °C to +125 °C	XQFN8	XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.4 $\times$ 1.2 $\times$ 0.5 mm	SOT1309-1

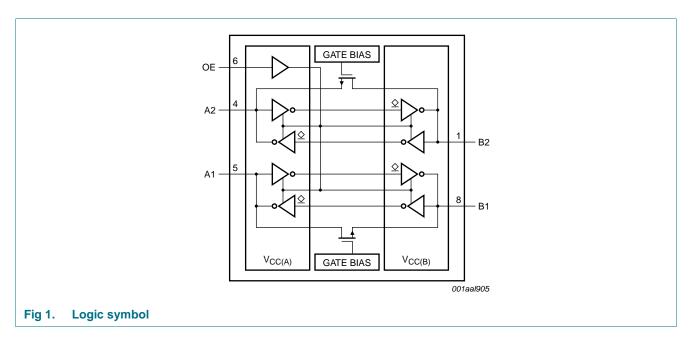
# 5. Marking

#### Table 2. Marking

Type number	Marking code
NTS0102DP	s02
NTS0102GT	s02
NTS0102GD	s02
NTS0102GF	s2
NTS0102GU	s2
NTS0102GU8	s2

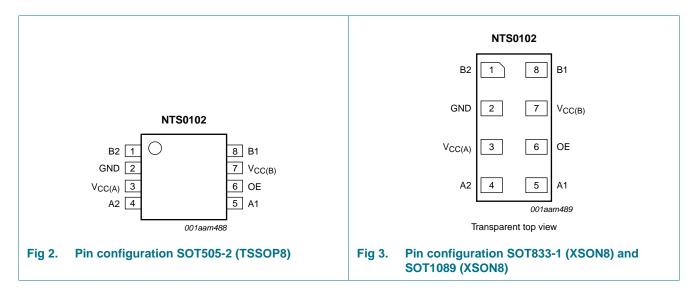
Dual supply translating transceiver; open drain; auto direction sensing

# 6. Functional diagram



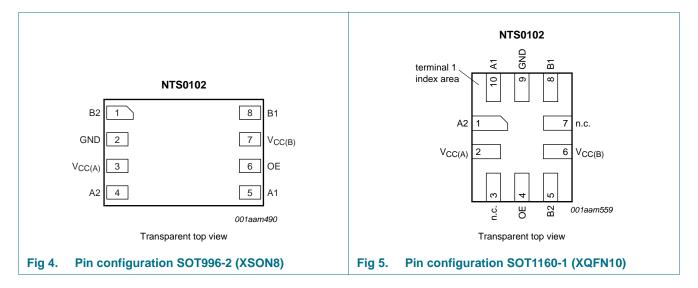
# 7. Pinning information

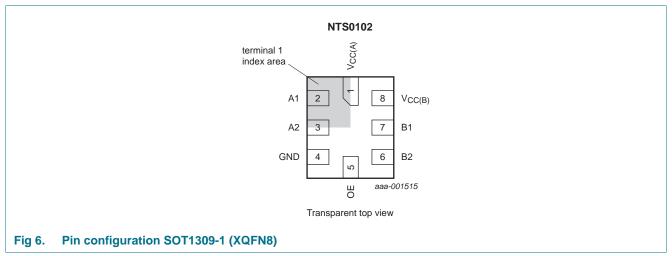
### 7.1 Pinning



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# 7.2 Pin description

Table 3. Pin description

Symbol	Pin			Description
	SOT505-2, SOT833-1, SOT1089 and SOT996-2	SOT1160-1	SOT1309	
B2, B1	1, 8	5, 8	6, 7	data input or output (referenced to V <sub>CC(B)</sub> )
GND	2	9	4	ground (0 V)
$V_{CC(A)}$	3	2	1	supply voltage A
A2, A1	4, 5	1, 10	3, 2	data input or output (referenced to $V_{CC(A)}$ )
OE	6	4	5	output enable input (active HIGH; referenced to $V_{\text{CC(A)}})$
V <sub>CC(B)</sub>	7	6	8	supply voltage B
n.c.	-	3, 7	-	not connected

# 8. Functional description

Table 4. Function table[1]

Supply voltage		Input	Input/output	
V <sub>CC(A)</sub> V <sub>CC(B)</sub>		OE	An	Bn
1.65 V to V <sub>CC(B)</sub>	2.3 V to 5.5 V	L	Z	Z
1.65 V to V <sub>CC(B)</sub>	2.3 V to 5.5 V	Н	input or output	output or input
GND[2]	GND[2]	X	Z	Z

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

# 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+6.5	V
$V_{CC(B)}$	supply voltage B		-0.5	+6.5	V
VI	input voltage	A port and OE input	[1][2] -0.5	+6.5	V
		B port	[1][2] -0.5	+6.5	V
Vo	output voltage	Active mode	[1][2]		
		A or B port	-0.5	$V_{CCO} + 0.5$	V
		Power-down or 3-state mode	<u>[1]</u>		
		A port	-0.5	+4.6	V
		B port	-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Io	output current	$V_O = 0 V \text{ to } V_{CCO}$	[2] _	±50	mA
I <sub>CC</sub>	supply current	$I_{CC(A)}$ or $I_{CC(B)}$	-	100	mA

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<sup>[2]</sup> When either  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into power-down mode.

#### Dual supply translating transceiver; open drain; auto direction sensing

Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$I_{GND}$	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	<u>[3]</u> _	250	mW

<sup>[1]</sup> The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

For XSON8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

For XQFN10 package: above 128 °C the value of Ptot derates linearly with 11.5 mW/K.

For XQFN8 package: above 105.5 °C the value of Ptot derates linearly with 5.6 mW/K.

# 10. Recommended operating conditions

Table 6. Recommended operating conditions[1][2]

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		1.65	3.6	V
$V_{CC(B)}$	supply voltage B		2.3	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	A or B port; push-pull driving			
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	-	10	ns/V
		OE input			
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	-	10	ns/V

<sup>[1]</sup> The A and B sides of an unused I/O pair must be held in the same state, both at  $V_{CCI}$  or both at GND.

#### 11. Static characteristics

Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>I</sub>	input leakage current	OE input; $V_I$ = 0 V to 3.6 V; $V_{CC(A)}$ = 1.65 V to 3.6 V; $V_{CC(B)}$ = 2.3 V to 5.5 V	-	-	±1	μΑ
l <sub>OZ</sub>	OFF-state output current	A or B port; $V_O$ = 0 V or $V_{CCO}$ ; $V_{CC(A)}$ = 1.65 V to 3.6 V; $V_{CC(B)}$ = 2.3 V to 5.5 V	<u>[1]</u> _	-	±1	μΑ
I <sub>OFF</sub>	power-off leakage current	A port; $V_1$ or $V_O = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 0$ V to 5.5 V	-	-	±1	μΑ
		B port; $V_1$ or $V_0 = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 0$ V to 3.6 V	-	-	±1	μΑ
Cı	input capacitance	OE input; $V_{CC(A)} = 3.3 \text{ V}$ ; $V_{CC(B)} = 3.3 \text{ V}$	-	1	-	pF

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<sup>[2]</sup> V<sub>CCO</sub> is the supply voltage associated with the output.

<sup>[3]</sup> For TSSOP8 package: above 55  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K.

<sup>[2]</sup>  $V_{CC(A)}$  must be less than or equal to  $V_{CC(B)}$ .

#### Dual supply translating transceiver; open drain; auto direction sensing

 Table 7.
 Typical static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$C_{I/O}$	input/output	ut A port	-	5	-	pF
	capacitance	B port	-	8.5	-	pF
		A or B port; $V_{CC(A)} = 3.3 \text{ V}$ ; $V_{CC(B)} = 3.3 \text{ V}$	-	11	-	pF

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

#### Table 8. Typical supply current

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb}$  = 25 °C.

V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	Unit						
	2.5 V		3.3 V		5.0 V			
	I <sub>CC(A)</sub> I <sub>CC(B)</sub> I <sub>C</sub>		I <sub>CC(A)</sub>	I <sub>CC(B)</sub>	I <sub>CC(A)</sub>	I <sub>CC(A)</sub> I <sub>CC(B)</sub>		
1.8 V	0.1	0.5	0.1	1.5	0.1	4.6	μΑ	
2.5 V	0.1	0.1	0.1	0.8	0.1	3.8	μΑ	
3.3 V	-	-	0.1	0.1	0.1	2.8	μΑ	

#### Table 9. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40 °C to	o +85 °C	-40 °C to	Unit	
				Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	A port						
		$V_{CC(A)} = 1.65 \text{ V to } 1.95 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	<u>1]</u>	V <sub>CCI</sub> - 0.2	-	V <sub>CCI</sub> – 0.2	-	V
	$V_{CC(A)} = 2.3 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	1]	V <sub>CCI</sub> – 0.4	-	V <sub>CCI</sub> – 0.4	-	V	
		B port						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	1]	V <sub>CCI</sub> - 0.4	-	V <sub>CCI</sub> - 0.4	-	V
		OE input						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		0.65V <sub>CC(A)</sub>	-	0.65V <sub>CC(A)</sub>	-	V
V <sub>IL</sub>	LOW-level	A or B port						
	input voltage	$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	0.15	-	0.15	V
		OE input						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	0.35V <sub>CC(A)</sub>	-	0.35V <sub>CC(A)</sub>	V
$V_{OH}$	HIGH-level	$I_{O} = -20 \mu A$						
	output voltage	$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	2]	0.67V <sub>CCO</sub>	-	0.67V <sub>CCO</sub>	-	V
V <sub>OL</sub>	LOW-level	A or B port; $I_O = 1 \text{ mA}$	2]					
	output voltage	$V_{I} \le 0.15 \text{ V};$ $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	0.4	-	0.4	V

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#### Dual supply translating transceiver; open drain; auto direction sensing

**Table 9. Static characteristics** ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	arameter Conditions		-40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
				Min	Max	Min	Max	
Iı	input leakage current	OE input; $V_1 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	±2	-	±12	μΑ
l <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$	[2]	-	±2	-	±12	μΑ
0	power-off leakage	A port; $V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 0$ V to 5.5 V		-	±2	-	±12	μΑ
	current	B port; $V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 0$ V to 3.6 V		-	±2	-	±12	μА
I <sub>CC</sub>	supply current	$V_I = 0 \text{ V or } V_{CCI}; I_O = 0 \text{ A}$	<u>[1]</u>					
		I <sub>CC(A)</sub>						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	2.4	-	15	μА
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$		-	2.2	-	15	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 5.5 \text{ V}$		-	-1	-	-8	μΑ
		$I_{CC(B)}$						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	12	-	30	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$		-	-1	-	-5	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 5.5 \text{ V}$		-	1	-	6	μΑ
		$I_{CC(A)} + I_{CC(B)}$						
		$V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$		-	14.4	-	30	μΑ

<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the input.

# 12. Dynamic characteristics

Table 10. Dynamic characteristics for temperature range –40 °C to +85 °C[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9; for wave forms see Figure 7 and Figure 8.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>						
			2.5 V ± 0.2 V		3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.8 V ± 0.15 V								
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	4.6	-	4.7	-	5.8	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	6.8	-	6.8	-	7.0	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	4.4	-	4.5	-	4.7	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	5.3	-	4.5	-	0.5	ns

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<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

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Table 10. Dynamic characteristics for temperature range -40 °C to +85 °C[1] Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 9</u>; for wave forms see <u>Figure 7</u> and <u>Figure 8</u>.

Symbol	Parameter	Conditions				Vc	C(B)			Unit	
				2.5 V :	± 0.2 V		± 0.3 V	5.0 V :	± 0.5 V		
				Min	Max	Min	Max	Min	Max		
t <sub>en</sub>	enable time	OE to A; B		-	200	-	200	-	200	ns	
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	25	-	25	-	25	ns	
		OE to B; no external load	[2]	-	25	-	25	-	25	ns	
		OE to A		-	230	-	230	-	230	ns	
		OE to B		-	200	-	200	-	200	ns	
t <sub>TLH</sub> LOW to HIGH		A port		3.2	9.5	2.3	9.3	1.8	7.6	ns	
	output transition time	B port		3.3	10.8	2.7	9.1	2.7	7.6	ns	
t <sub>THL</sub>		A port		2.0	5.9	1.9	6.0	1.7	13.3	ns	
	output transition time	B port		2.9	7.6	2.8	7.5	2.8	10.0	ns	
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.7	-	0.7	-	0.7	ns	
$t_{W}$	pulse width	data inputs		20	-	20	-	20	-	ns	
f <sub>data</sub>	data rate			-	50	-	50	-	50	Mbps	
$V_{CC(A)} =$	2.5 V ± 0.2 V										
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		-	3.2	-	3.3	-	3.4	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		-	3.5	-	4.1	-	4.4	ns	
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		-	3.0	-	3.6	-	4.3	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		-	2.5	-	1.6	-	0.7	ns	
t <sub>en</sub>	enable time	OE to A; B		-	200	-	200	-	200	ns	
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	20	-	20	-	20	ns	
		OE to B; no external load	[2]	-	20	-	20	-	20	ns	
		OE to A		-	200	-	200	-	200	ns	
		OE to B		-	200	-	200	-	200	ns	
t <sub>TLH</sub>	LOW to HIGH	A port		2.8	7.4	2.6	6.6	1.8	6.2	ns	
	output transition time	B port		3.2	8.3	2.9	7.9	2.4	6.8	ns	
$t_{THL}$	HIGH to LOW	A port		1.9	5.7	1.9	5.5	1.8	5.3	ns	
	output transition time	B port		2.2	7.8	2.4	6.7	2.6	6.6	ns	
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.7	-	0.7	-	0.7	ns	
t <sub>W</sub>	pulse width	data inputs		20	-	20	-	20	-	ns	
f <sub>data</sub>	data rate			-	50	-	50	-	50	Mbps	
$V_{CC(A)} =$	3.3 V ± 0.3 V										
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		-	-	-	2.4	-	3.1	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		-	-	-	4.2	-	4.4	ns	

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#### Dual supply translating transceiver; open drain; auto direction sensing

Table 10. Dynamic characteristics for temperature range −40 °C to +85 °C[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9; for wave forms see Figure 7 and Figure 8.

Symbol	Parameter	Conditions				Vc	C(B)			Unit
				$2.5~V \pm 0.2~V$		3.3 V :	$3.3~V\pm0.3~V$		5.0 V ± 0.5 V	
				Min	Max	Min	Max	Min	Max	
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		-	-	-	2.5	-	3.3	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		-	-	-	2.5	-	2.6	ns
t <sub>en</sub>	enable time	OE to A; B		-	-	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	-	15	-	15	ns
		OE to B; no external load	[2]	-	-	-	15	-	15	ns
		OE to A		-	-	-	260	-	260	ns
		OE to B		-	-	-	200	-	200	ns
t <sub>TLH</sub>	LOW to HIGH	A port		-	-	2.3	5.6	1.9	5.9	ns
	output transition time	B port		-	-	2.5	6.4	2.1	7.4	ns
t <sub>THL</sub>	HIGH to LOW	A port		-	-	2.0	5.4	1.9	5.0	ns
output transition time	•	B port		-	-	2.3	7.4	2.4	7.6	ns
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	-	-	0.7	-	0.7	ns
t <sub>W</sub>	pulse width	data inputs		-	-	20	-	20	-	ns
f <sub>data</sub>	data rate			-	-	-	50	-	50	Mbps

<sup>[1]</sup>  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 9</u>; for wave forms see <u>Figure 7</u> and <u>Figure 8</u>.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>						
			$2.5~V\pm0.2~V$		$3.3~V\pm0.3~V$		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.8 V ± 0.15 V								
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	5.8	-	5.9	-	7.3	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	8.5	-	8.5	-	8.8	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	5.5	-	5.7	-	5.9	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	6.7	-	5.7	-	0.7	ns
t <sub>en</sub>	enable time	OE to A; B	-	200	-	200	-	200	ns

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<sup>[2]</sup> Delay between OE going LOW and when the outputs are actually disabled.

<sup>[3]</sup> Skew between any two outputs of the same package switching in the same direction.

#### Dual supply translating transceiver; open drain; auto direction sensing

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C[1] ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 9</u>; for wave forms see <u>Figure 7</u> and <u>Figure 8</u>.

Symbol	Parameter	Conditions				V <sub>C</sub>	C(B)			Unit
				2.5 V	± 0.2 V	3.3 V :	± 0.3 V	5.0 V	± 0.5 V	
				Min	Max	Min	Max	Min	Max	
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	30	-	30	-	30	ns
		OE to B; no external load	[2]	-	30	-	30	-	30	ns
		OE to A		-	250	-	250	-	250	ns
		OE to B		-	220	-	220	-	220	ns
t <sub>TLH</sub>	LOW to HIGH	A port		3.2	11.9	2.3	11.7	1.8	9.5	ns
	output transition time	B port		3.3	13.5	2.7	11.4	2.7	9.5	ns
t <sub>THL</sub>	HIGH to LOW	A port		2.0	7.4	1.9	7.5	1.7	16.7	ns
	output transition time	B port		2.9	9.5	2.8	9.4	2.8	12.5	ns
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	8.0	-	0.8	-	8.0	ns
t <sub>W</sub>	pulse width	data inputs		20	-	20	-	20	-	ns
f <sub>data</sub>	data rate			-	50	-	50	-	50	Mbps
$V_{CC(A)} =$	2.5 V ± 0.2 V									
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		-	4.0	-	4.2	-	4.3	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		-	4.4	-	5.2	-	5.5	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		-	3.8	-	4.5	-	5.4	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		-	3.2	-	2.0	-	0.9	ns
t <sub>en</sub>	enable time	OE to A; B		-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	25	-	25	-	25	ns
		OE to B; no external load	[2]	-	25	-	25	-	25	ns
		OE to A		-	220	-	220	-	220	ns
		OE to B		-	220	-	220	-	220	ns
t <sub>TLH</sub>	LOW to HIGH	A port		2.8	9.3	2.6	8.3	1.8	7.8	ns
	output transition time	B port		3.2	10.4	2.9	9.7	2.4	8.3	ns
t <sub>THL</sub>	HIGH to LOW	A port		1.9	7.2	1.9	6.9	1.8	6.7	ns
	output transition time	B port		2.2	9.8	2.4	8.4	2.6	8.3	ns
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.8	-	0.8	-	0.8	ns
t <sub>W</sub>	pulse width	data inputs		20	-	20	-	20	-	ns
f <sub>data</sub>	data rate			-	50	-	50	-	50	Mbps
V <sub>CC(A)</sub> =	3.3 V ± 0.3 V									
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		-	-	-	3.0	-	3.9	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		-	-	-	5.3	-	5.5	ns

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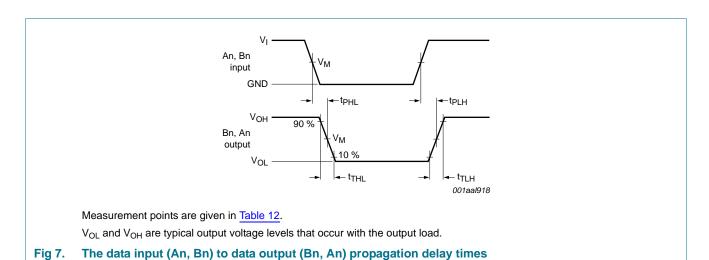
#### Dual supply translating transceiver; open drain; auto direction sensing

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C $\frac{[1]}{}$  ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9; for wave forms see Figure 7 and Figure 8.

•	0 10	10	<i>"</i>								
Symbol	Parameter	Conditions				V <sub>C</sub>	C(B)			Unit	
				2.5 V =	Ŀ 0.2 V	3.3 V =	± 0.3 V	5.0 V	± 0.5 V		
				Min	Max	Min	Max	Min	Max		
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	'	-	-	-	3.2	-	4.2	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		-	-	-	3.2	-	3.3	ns	
t <sub>en</sub>	enable time	OE to A; B		-	-	-	200	-	200	ns	
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	-	20	-	20	ns	
		OE to B; no external load	[2]	-	-	-	20	-	20	ns	
		OE to A		-	-	-	280	-	280	ns	
		OE to B		-	-	-	220	-	220	ns	
t <sub>TLH</sub>	LOW to HIGH	A port		-	-	2.3	7.0	1.9	7.4	ns	
	output transition time	B port		-	-	2.5	8.0	2.1	9.3	ns	
$t_{THL}$	HIGH to LOW	A port		-	-	2.0	6.8	1.9	6.3	ns	
output transition time	output transition time	B port		-	-	2.3	9.3	2.4	9.5	ns	
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	-	-	0.8	-	0.8	ns	
t <sub>W</sub>	pulse width	data inputs		-	-	20	-	20	-	ns	
f <sub>data</sub>	data rate			-	-	-	50	-	50	Mbps	

<sup>[1]</sup>  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

# 13. Waveforms

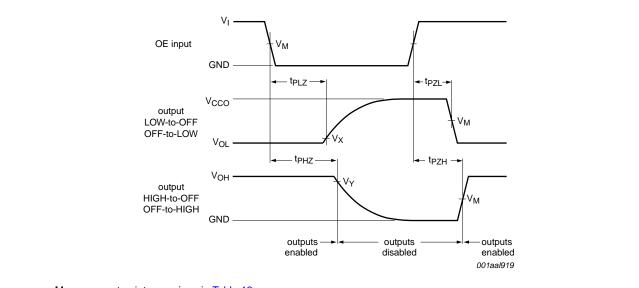


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<sup>[2]</sup> Delay between OE going LOW and when the outputs are actually disabled.

<sup>[3]</sup> Skew between any two outputs of the same package switching in the same direction.

#### Dual supply translating transceiver; open drain; auto direction sensing



Measurement points are given in Table 12.

 $\ensuremath{V_{OL}}$  and  $\ensuremath{V_{OH}}$  are typical output voltage levels that occur with the output load.

Fig 8. Enable and disable times

Table 12. Measurement points[1][2]

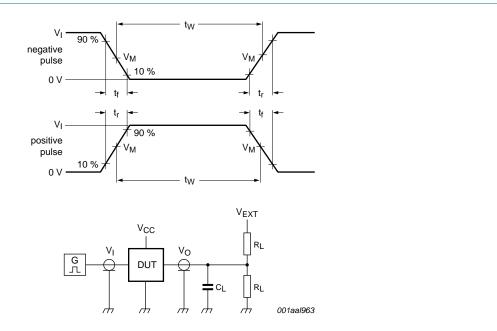
Supply voltage	Input	Output	Output						
V <sub>cco</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>					
$1.8~\textrm{V} \pm 0.15~\textrm{V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V					
$2.5~\text{V} \pm 0.2~\text{V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V					
3.3 V $\pm$ 0.3 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$					
$5.0~V\pm0.5~V$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.3 V	$V_{OH} - 0.3 V$					

<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the input.

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<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

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Test data is given in Table 13.

All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz;  $Z_0 = 50~\Omega$ ; dV/dt  $\geq$  1.0 V/ns.

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 13. Test data

Supply voltage		Input		Load		V <sub>EXT</sub>			
V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	V <sub>I</sub> [1]	Δt/ΔV	CL	R <sub>L</sub> [2]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> [3]	
1.65 V to 3.6 V	2.3 V to 5.5 V	$V_{\text{CCI}}$	$\leq$ 1.0 ns/V	15 pF	50 kΩ, 1 MΩ	open	open	2V <sub>CCO</sub>	

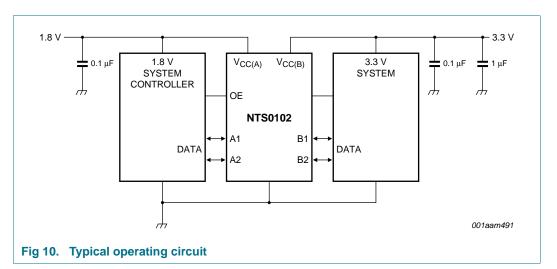
- [1]  $V_{CCI}$  is the supply voltage associated with the input.
- [2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, R<sub>L</sub> = 1 MΩ; for measuring enable and disable times, R<sub>L</sub> = 50 KΩ.
- [3] V<sub>CCO</sub> is the supply voltage associated with the output.

Dual supply translating transceiver; open drain; auto direction sensing

# 14. Application information

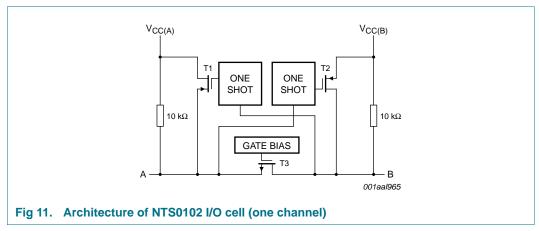
#### 14.1 Applications

Voltage level-translation applications. The NTS0102 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is primarily targeted at I<sup>2</sup>C or 1-wire which use open-drain drivers, it may also be used in applications where push-pull drivers are connected to the ports, however the NTB0102 may be more suitable.



#### 14.2 Architecture

The architecture of the NTS0102 is shown in <u>Figure 11</u>. The device does not require an extra input signal to control the direction of data flow from A to B or B to A.



The NTS0102 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

- 1. A pass-gate transistor (N-channel) that ties the ports together.
- 2. An output edge-rate accelerator that detects and accelerates rising edges on the I/O pins.

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The gate bias voltage of the pass gate transistor (T3) is set at approximately one threshold voltage above the  $V_{CC}$  level of the low-voltage side. During a LOW-to-HIGH transition the output one-shot accelerates the output transition by switching on the PMOS transistors (T1, T2) bypassing the 10  $k\Omega$  pull-up resistors and increasing current drive capability. The one-shot is activated once the input transition reaches approximately  $V_{CCI}/2$ ; it is de-activated approximately 50 ns after the output reaches  $V_{CCO}/2$ . During the acceleration time the driver output resistance is between approximately 50  $\Omega$  and 70  $\Omega$ . To avoid signal contention and minimize dynamic  $I_{CC}$ , the user should wait for the one-shot circuit to turn-off before applying a signal in the opposite direction. Pull-up resistors are included in the device for DC current sourcing capability.

#### 14.3 Input driver requirements

As the NTS0102 is a switch type translator, properties of the input driver directly effect the output signal. The external open-drain or push-pull driver applied to an I/O determines the static current sinking capability of the system; the max data rate, HIGH-to-LOW output transition time ( $t_{THL}$ ) and propagation delay ( $t_{PHL}$ ) are dependent upon the output impedance and edge-rate of the external driver. The limits provided for these parameters in the datasheet assume a driver with output impedance below 50  $\Omega$  is used.

#### 14.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration. In cases with very heavy capacitive loading there is a risk that the output will not reach the positive rail within the one-shot pulse duration.

To avoid excessive capacitive loading and to ensure correct triggering of the one-shot it's recommended to use short trace lengths and low capacitance connectors on NTS0102 PCB layouts. To ensure low impedance termination and avoid output signal oscillations and one-shot re-triggering, the length of the PCB trace should be such that the round trip delay of any reflection is within the one-shot pulse duration (approximately 50 ns).

#### 14.5 Power up

During operation  $V_{CC(A)}$  must never be higher than  $V_{CC(B)}$ , however during power-up  $V_{CC(A)} \ge V_{CC(B)}$  does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NTS0102 includes circuitry that disables all output ports when either  $V_{CC(A)}$  or  $V_{CC(B)}$  is switched off.

#### 14.6 Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW

causes all I/Os to assume the high-impedance OFF-state. The disable time ( $t_{dis}$  with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time ( $t_{en}$ ) indicates the amount of time the user must allow for one one-shot circuitry to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor, the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Dual supply translating transceiver; open drain; auto direction sensing

### 14.7 Pull-up or pull-down resistors on I/Os lines

Each A port I/O has an internal 10 k $\Omega$  pull-up resistor to  $V_{CC(A)}$ , and each B port I/O has an internal 10 k $\Omega$  pull-up resistor to  $V_{CC(B)}$ . If a smaller value of pull-up resistor is required, an external resistor must be added parallel to the internal 10 k $\Omega$ , this will effect the  $V_{OL}$  level. When OE goes LOW the internal pull-ups of the NTS0102 are disabled.

Dual supply translating transceiver; open drain; auto direction sensing

# 15. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

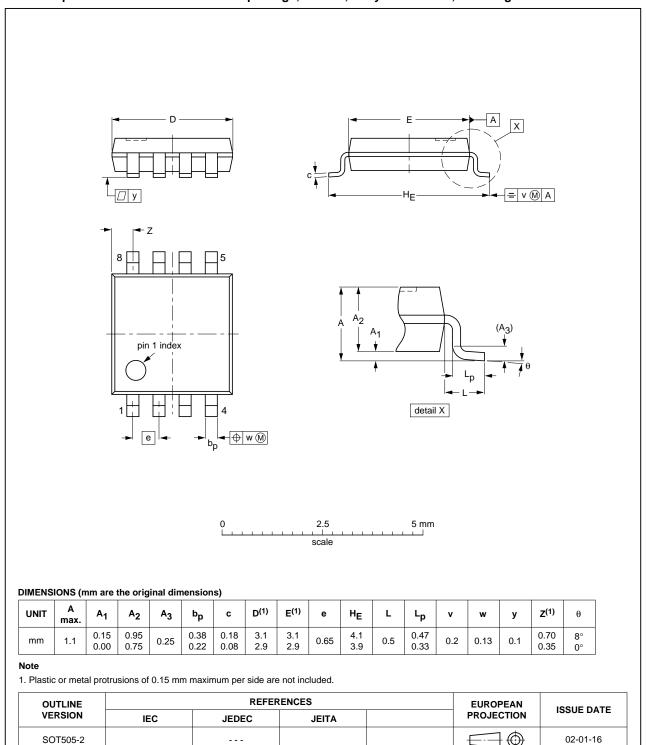


Fig 12. Package outline SOT505-2 (TSSOP8)

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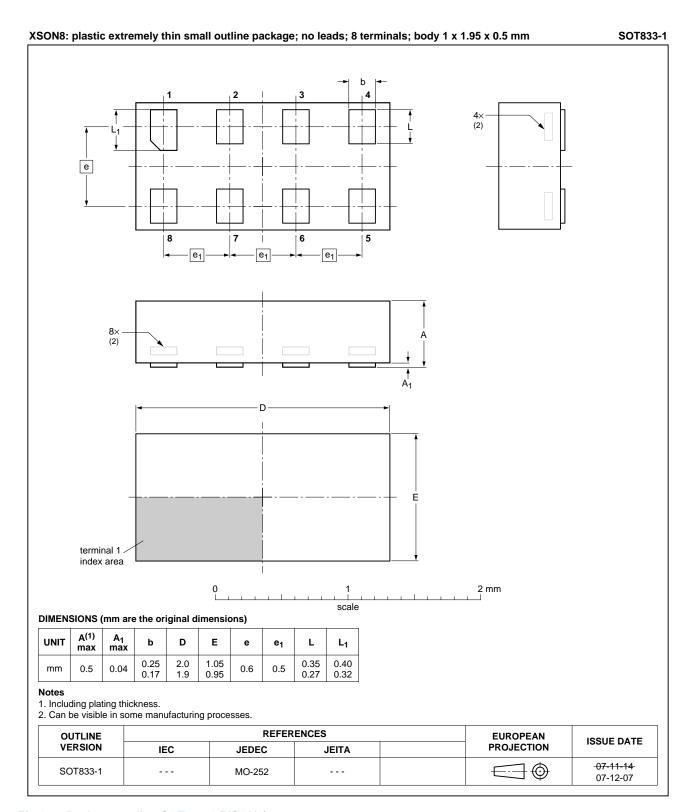


Fig 13. Package outline SOT833-1 (XSON8)

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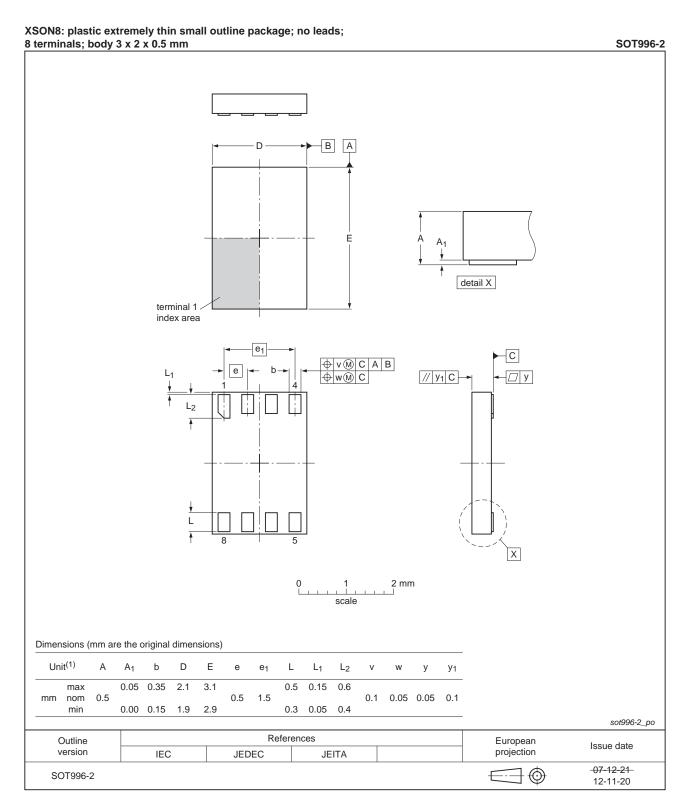


Fig 14. Package outline SOT996-2 (XSON8)

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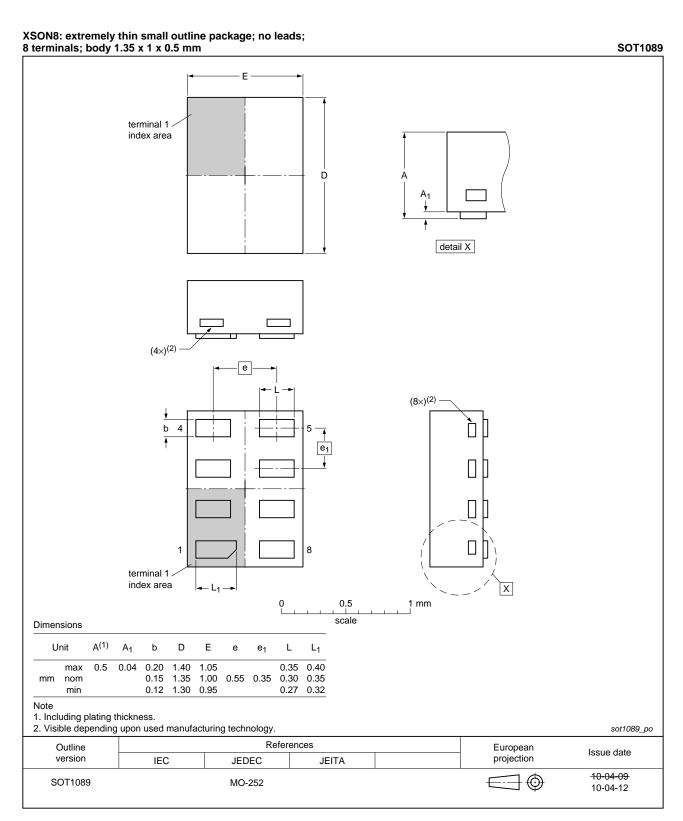


Fig 15. Package outline SOT1089 (XSON8)

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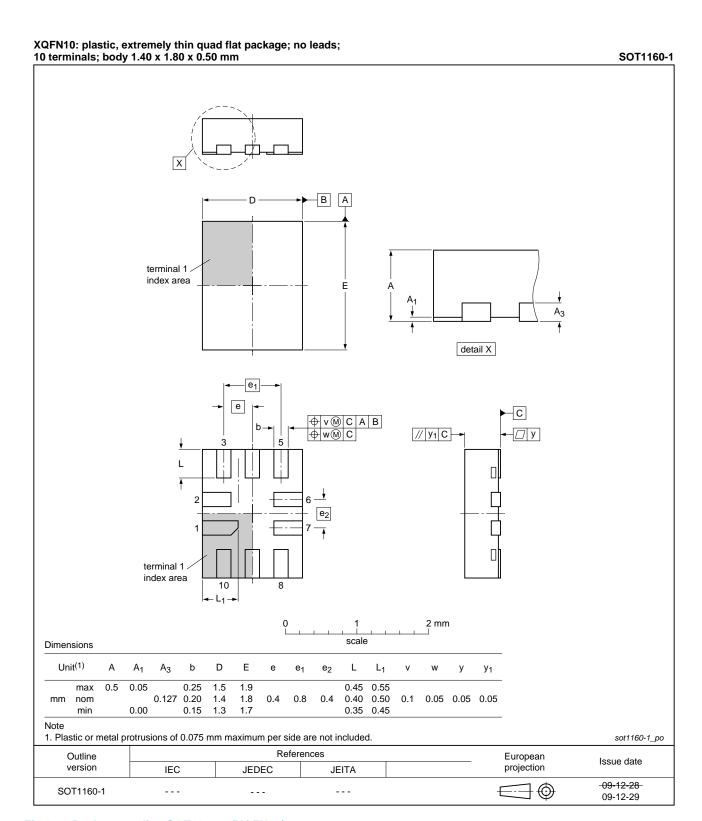


Fig 16. Package outline SOT1160-1 (XQFN10)

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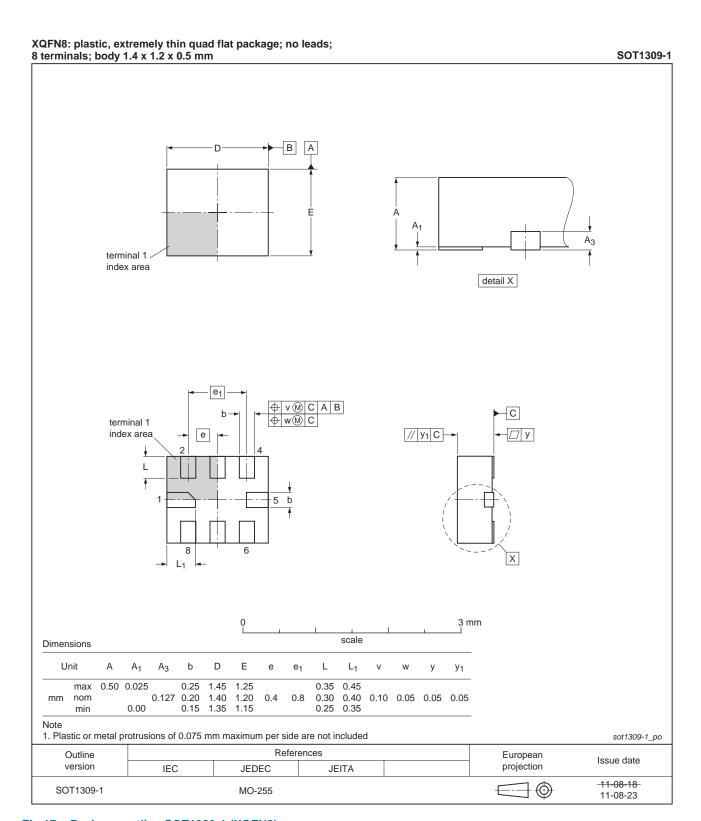


Fig 17. Package outline SOT1309-1 (XQFN8)

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**Product data sheet** 

### Dual supply translating transceiver; open drain; auto direction sensing

# 16. Abbreviations

#### Table 14. Abbreviations

Acronym	Description
•	•
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
GPIO	General Purpose Input Output
HBM	Human Body Model
I <sup>2</sup> C	Inter-Integrated Circuit
MM	Machine Model
PCB	Printed Circuit Board
PMOS	Positive Metal Oxide Semiconductor
SMBus	System Management Bus
UART	Universal Asynchronous Receiver Transmitter
UTLP	Ultra Thin Leadless Package

# 17. Revision history

#### Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NTS0102 v.4	20130123	Product data sheet	-	NTS0102 v.3
Modifications:	<ul> <li>For type num</li> </ul>	ber NTS0102GD XSON8U ha	as changed to XSON8.	
NTS0102 v.3	20111117	Product data sheet	-	NTS0102 v.2
Modifications:	<ul> <li>Added type n</li> </ul>	umber NTS0102GU8 (SOT13	809-1/XQFN8 package	).
NTS0102 v.2	20110411	Product data sheet	-	NTS0102 v.1
NTS0102 v.1	20100921	Product data sheet	-	-

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### 18. Legal information

#### 18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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